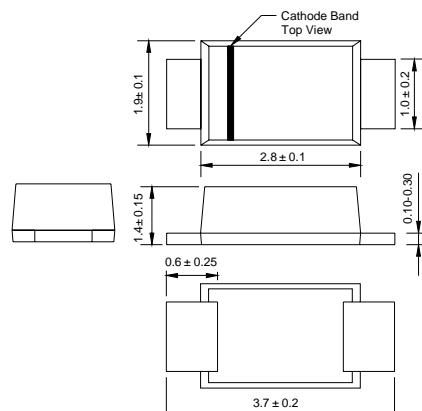




Features

- Low profile space
- Ideal for automated placement
- Glass passivated chip junctions
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High temperature soldering:
260 °C/10 seconds at terminals
- Component in accordance to
RoHS 2002/95/1 and WEEE 2002/96/EC

SOD-123FL



Dimensions in millimeters

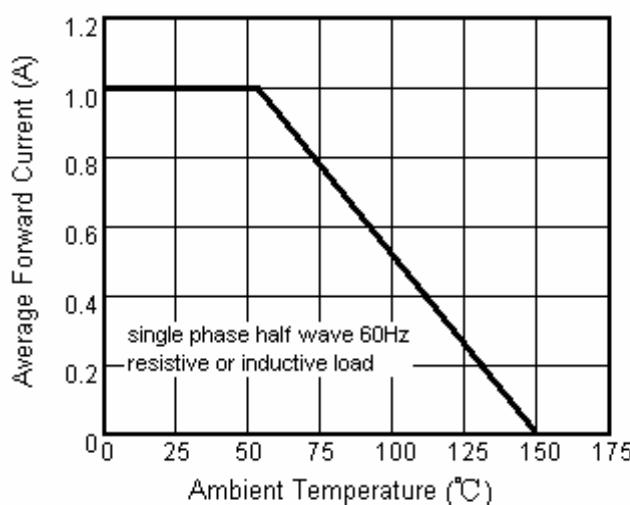
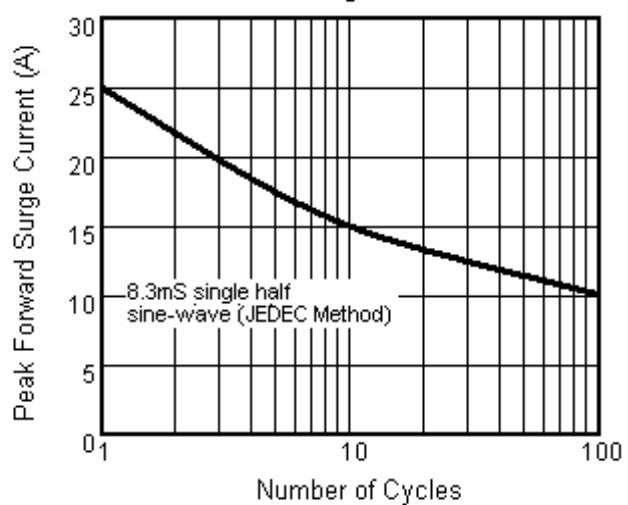
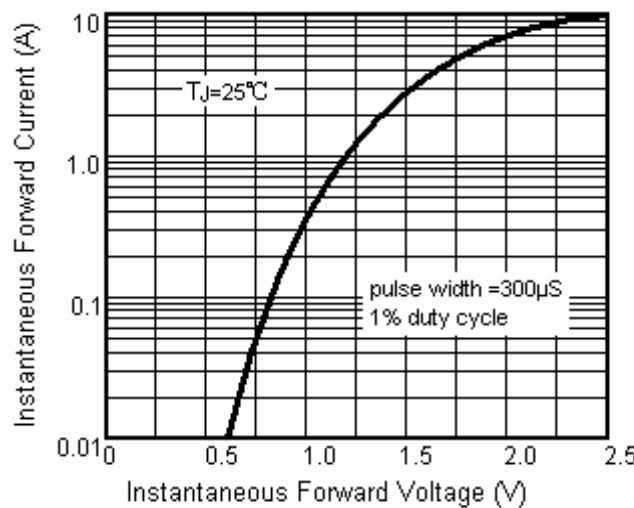
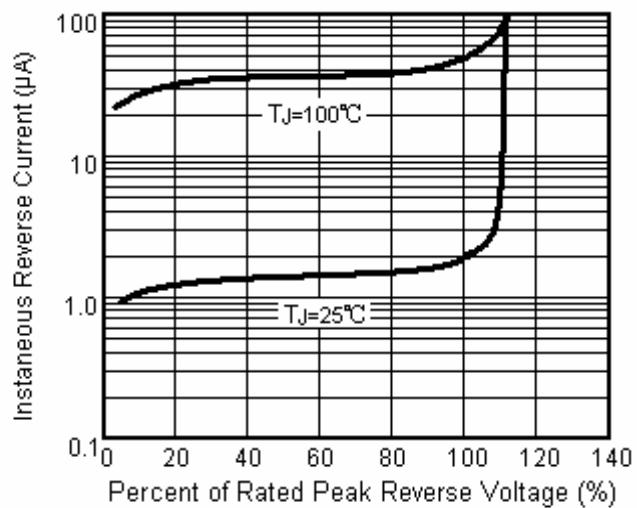
Mechanical Data

- **Case:** JEDEC SOD-123FL molded plastic body over glass passivated chip
- **Terminals:** Solder plated, solderable per J-STD-002B and JESD22-B102D
- **Polarity:** Laser band denotes cathode end

Maximum Ratings & Thermal Characteristics & Electrical Characteristics

(TA = 25 °C unless otherwise noted)

	Symbol	DFR1A	DFR1B	DFR1D	DFR1G	DFR1J	DFR1K	DFR1M	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current	I _{F(AV)}				1				A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}				25				A
Maximum instantaneous forward voltage at 1.0A	V _F				1.3				V
Maximum DC reverse current T _A = 25 °C at Rated DC blocking voltage T _A = 100°C	I _R				5.0				µ A
Maximum reverse recovery time at I _F = 0.5 A , I _R = 1.0 A , I _{rr} = 0.25 A	t _{rr}		150		250		500		nS
Typical junction capacitance at 4.0 V ,1MHz	C _J			15					p F
Operating junction and storage temperature range	T _J , T			-55 to +150					°C

Characteristic Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)
Fig.1 Forward Current Derating Curve

Fig.2 Maximum Non-Repetitive Peak Forward Surge Current

Fig.3 Typical Instantaneous Forward Characteristics

Fig.4 Typical Reverse Characteristics

Fig.5 Typical Junction Capacitance
